

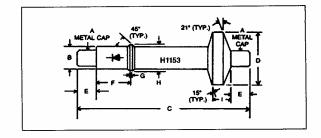
High Voltage Diode H1153

Designed for High Temperature Operation Low RFI/EMI



LTR.	INCHES	MILLIMETERS		
Α	.360 Dia.	9,14 Dia.		
В	.50 Dia.	12,70 Dia.		
С	3.7	94		
D	1.18 Dia.	29,97 Dia.		
E	.4	10,2		
F	.750	19,05		
G	.050	1,27		
Н	.60 Dia.	15,24		
- 1	.40	10,16		

Dimensional Tolerances .X \pm .1, .XX \pm .02, .XXX \pm .005 inch.



MAXIMUM RATINGS (At T_A = 25°C unless otherwise noted)

RATING	SYMBOL		UNITS
Repetitive Peak Reverse Voltage See Fig. 1 & 2	V _{RRM}	45	KV
Average Forward Current (Fig. 1)	1 _{F(AV)}	2.2	mA
Peak Surge Current, 1/2 Cycle at 60Hz, (Non-Rep)	I _{FSM}	200	mA
Maximum Ambient Operating Temperature	T _A	90	°C
These maximum ratings cannot necessarily be used simultaneously; see Fig. 1—Safe Operating Areas.			

ELECTRICAL CHARACTERISTICS (At T_A = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL		UNITS
Maximum Reverse Current at V _B = 45kV	I _R	1	μA
Maximum Forward Voltage Drop at I _F = 5mA	V _{FM}	180	V
Max. Anode to Cathode Capacitance at V _B = 400V, F = 100kHz	C _J	0.75	pF
Max. Reverse Recovery Time, $I_F=2\text{mA}$, $I_R=-4\text{mA}$ and $I_{RR}=-1\text{mA}$ (Fig. 3)	t,	175	nsec



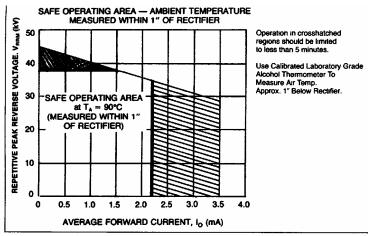


FIGURE 1

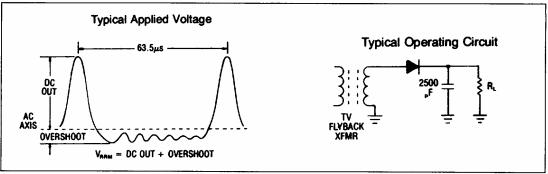


FIGURE 2

